ITSKEVICH, YE.S

8/056/60/038/02/07/061 B006/B011

24.7600 AUTHOR:

Specific Heat of Bismuth Telluride at Low Temperatures Zhurnal eksperimentalinoy i teoreticheskoy fiziki, 1960, Itakevich, Ye. S.

TITLE:

TEXT: The present paper reports on measurements of the specific heat of paper reports on measurements of the specific heat of the speci The present paper reports on measurements of the specific heat of the preparation had been supplied between 1.37 and 65°K. The preparation had been supplied by the Translation had by the Translation had been supplied by the Translation had by the Translation had been su by the Institut poluprovodnikov AN SSSR (Institute of Semiconductors of the AS USSR). It was recrystallized twice to increase its degree of PERIODICAL: by the Institut poluprovodnikov AN SSSH (Institute of Semiconductors the AS USSR) at was recrystallized twice to increase its degree of the AS USSR) at was recrystallized twice of increase and an armination of impurities was omitted. Slides were sulfated to increase the semination of impurities was omitted. the AS USSRIA It was recrystallized twice to increase its degree of purity; a determination of impurities was omitted. Slices were the purity; a determination of impurities was object and resistivity the off from a coarse-crystalline ovlindrical block. purity; a determination of impurities was omitted. Stices were spilt therough of from a coarse-crystalline cylindrical block, and resistivity, of from a coarse-crystalline were measured on them. 135 measurements off from a coarse-crystalline collindrical block, and resistivity, ther mosemf, and the Hall constant were measured on them. 135 measurements and the specific heat of biamuth telluride were made between 1.37 and mo-omf, and the Hall constant were measured on them. 137 measurements of the specific heat of bismuth telluride were made 1 171 measurements of the specific heat of bismuth telluride were 1 171 measurements and 1 171 measurements. of the specific heat of bismuth telluride were made petween 1.91 and 64.80 k. No phase transitions were established. Fig. 1 illustrates by surements made in the range of 1.37 = 20.00 k; the results diagram. Below Petrov are also shown in this diagram. P. V. Gulityayev and A. V. Petrov are also shown in this diagram. gurements made in the range of 1.37 = 20.0 K; the results obtained by P. V. Gulitysyev and A. V. Petrov are also shown in this diagram. Below

Card 1/3

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s/056/60/038/02/07/061 Specific Heat of Bismuth Telluride at Low B006/B011

2.30K the results can be described by C = 7T + 464.5(T/9)3, where y = (17+8).10⁻⁵ joule.deg /gram-atom, and 0 = (155.5 ± 3) K is the Debye temperature at absolute zero. In the range between 2.5 and 8 K the range of the range Temperatures the power exponent in the temperature dependence of the specific heat is greater than 3. Fig. 3 shows the characteristic Debye temperature between 1.37 and 50°K as a function of temperature. 9D at first ex-

hibits & steep decline at low temperatures, runs through a minimum at about 80K, and again slowly rises with further rising temperature. Results of measurements on resistivity are compiled in Table 1. Fig. 4 illustrates the temperature dependence of resistivity in the range 2 - 300°K. Table 2 specifies absolute values of the emf and the Hall constant R, Fig. 5 shows R(T) in Bi 2Te 3. 19 =3 R = 3 \(\text{8 ne or n = 7.35.10} \) R = 4.0.10 \(\text{10 m} \) and an energia heat measure of holes and energia heat measure of heat me

N = JR/ORE OF R = (.)) TO R 9 R = 4.0 TO CM . The hole mass m at ?
Was calculated from the concentration of holes and specific heat measurements. C = yT = 3.86.10 13 Vn1/3 (m/mo)T[cal/gram-atom.grad] holds,

where V denotes the atomic volume, n is the number of holes per unit

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8/076/61/035/008/012/016 B110/B101

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Itskevich, Ye. S. (Moscow)

AUTHOR: TITLE:

Thermodynamic investigations at low temperatures. XII. Specific heat of bismuth telluride between 1.4 and 65 K. Enthalpy and entropy of Bi2Te3 at 298.15 K

Zhurnal fizicheskoy khimii, v. 35, no. 8, 1961, 1813 - 1815

TEXT: In view of the interest raised by anisotropic crystals, the author measured the temperature dependence of the specific heat of Bi₂Te₃ having a stratified crystal lattice. The method had been earlier described by a stratilled crystal lattice. The method had been earlief described by the author (Zh. eksperim. i teor. fiz., 38, 351, 1960). Numerical values of specific heat, enthalpy, and entropy are given here. The temperature of specific heat, enthalpy, and entropy are given here. The temperature dependence of the specific heat below 10 K in Bi₂Te₃ differs from that of dependence of the specific heat below 10 K in Bi₂Te₃ other laminar lattice structures. Below the cubic-law region attained at 8 - 11°K the specific heat is proportional to T3.6. Only at T<2.5°K it becomes again proportional to T3. Conventional theories on laminar Card 1/5

CIA-RDP86-00513R000618920010-4" APPROVED FOR RELEASE: 08/10/2001

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Thermodynamic investigations ...

crystals would not lead one to expect this. Measurements are stopped at 8 K and the curve is extrapolated to absolute zero according to the oubic law with the Debye temperature $\Theta_d = 117^{\circ} K$ corresponding to this region (while $\Theta_d = \Theta_d$ (0) = 155.5 K). In this way, the molar entropy was found to be $S_{80K}^{\circ} = 1.04$ joules/degree (experimentally: $S_{8}^{\circ} = 0.90$ joules/degree). This is not to be explained by determination errors of entropy at the upper limit of measurement. Extrapolation must be done carefully, as the specific heat in the calculation of enthalpy and entropy is measured at 298.15 K, or from 11 K on at best, and from 11 K to 0 K extrapolation bases on the simplest assumptions. In bismuth telluride, an extrapolation that would take account of the stratified lattice structure would cause a large error. According to the author (Dis., In-t fizich. problem, M., 1957) the divergence between extrapolated and experimental values of CdI₂ and CdBr₂ at 11 K amounts to 25%. The figure presents the values measured by the author between 1.37 and 64.8 K as well as the values calculated by P. V. Gult'yayev., A. V. Petrov (Ref. 3: ZhFTT, 1, 368, 1959) between

Card 2/5

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S/076/61/035/008/012/016 B110/B101

Thermodynamic investigations...

80 and 300°K. The table supplies only the values, obtained by means of graphic smoothing, of the molar specific heat between 1.5 and 65°K, because the 135 points obtained were irregularly distributed in the temperature range. By integration, for entropy and enthalpy of Bi₂Te₃

were obtained, the upper limit of measurement being 65°K;

So = 84.76 ± 0.32 joules/deg.mole. In order to calculate entropy and enthalpy at 298.15°K, integrated data were used in the same manner;

So = 260.9 joules/deg.mole; House, 1 = 30908 joules/mole.

However, both results are approximate values, and it is difficult to estimate their error limits. There are 1 figure, 1 table, and 3 Soviet references.

ASSOCIATION: Akademiya nauk SSSR Institut fiziki vysokykh davleniy (Academy of Sciences USSR, Institute of High-pressure

Physics)

SUBMITTED:

December 30, 1959

Card 3/5

37863 \$/056/62/042/005/006/050 B125/B108

AUTHOR: . Itskevich, Ye. S.

TITLE: Electric resistivity of cerium at low temperatures and high pressures

PERIODICAL: Zhurnal eksperimental'noy i teoreticheskoy fiziki, v. 42, no. 5, 1962, 1173 - 1182

TEXT: The temperature dependence of the resistivity of two cerium samples was measured between 10 and 300°K at normal pressure and at pressures of up to 10,000 kg/cm². The samples, contained less than 0.75% needymium and praseodymium each, less than 0.02% iron, and less than 0.001% cadmium, lead, tin, and bismuth. Results are collected in Table 1 and Fig. 1. The changes in resistivity after transitions induced by temperature or pressure (10,000 kg/cm²) are identical. The resistivity of the facecentered cubic cerium lattice increases linearly with temperature between 50 and 300°K, with $Q_0^{-1}\Delta p/\Delta T = 3.12 \cdot 10^{-3}$ deg⁻¹. Between 10 and 40°K, resistivity increases in proportion with T^2 . The abnormal behavior of resistivity at 12.5°K, found by other authors, was not confirmed by the

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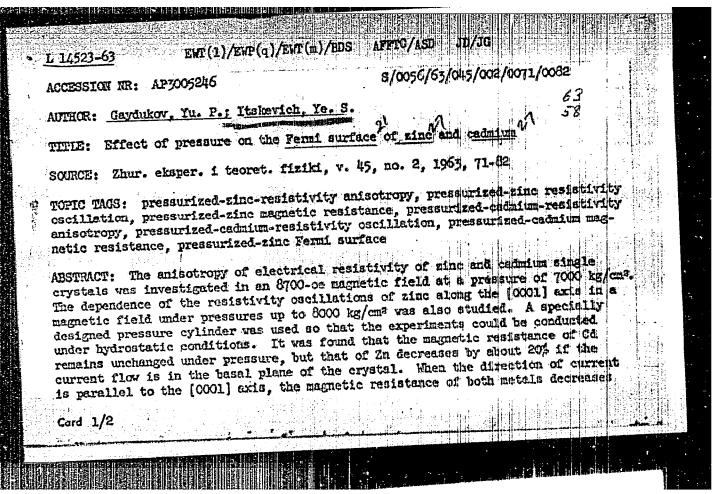
Electric resistivity of ...

present results. The branches of the cerium phase diagram probably are parallel below room temperature. The discontinuous change in Q in the transition from the face-centered cubic cerium lattice to the cubic lattice vanishes at about 5780k. The resistivity of compressed face-centered cerium has the same temperature coefficient as the majority of the metals in a wide temperature range. There are 5 figures and 2 tables.

ASSOCIATION: Institut fiziki vysokikh davleniy Akademii nauk SSSR (Institute of the Physics of High Pressures of the Academy of Sciences USSR)

SUBMITTED: December 14, 1961

Card 2/4 7



1. 14523-63 ACCESSION NR: AP3005246	fod in zinc decresses as pressure
by 35 to 40%. The resistivity oscillation per increases, from 6.3 x 10 ⁻⁵ oc ⁻¹ at atmospheric increases, from 6.3 x 10 ⁻⁵ oc ⁻¹ atmospheric increases, from 6.3 x 10 ⁻⁵ oc ⁻¹ atmospheric increases, from 6.3 x 10 ⁻⁵ oc ⁻¹ atmospheric increases, from 6.3 x 10 ⁻⁵ oc ⁻¹ atmospheric increases, from 6.3 x 10 ⁻⁵ oc ⁻¹ atmospheric increases, from 6.3 x 10 ⁻⁵ oc ⁻¹ atmospheric increases, from 6.3 x 10 ⁻⁵ oc ⁻¹ atmospheric increases, from 6.3 x 10 ⁻⁵ oc ⁻¹ atmospheric increases, from 6.3 x 10 ⁻⁵ oc ⁻¹ atmospheric increases, from 6.3 x 10 ⁻⁵ oc ⁻¹ atmospheric increases, from 6.3 x 10 ⁻⁵ oc ⁻¹ atmospheric increases, from 6.3 x 10 ⁻⁵ oc ⁻¹ atmospheric increases, from 6.3 x 10 ⁻⁵ oc ⁻¹ atmospheric increases, from 6.3 x 10 ⁻⁵ oc ⁻¹ atmospheric in	s of the data obtained. The critical
pressure at which the authors thank Academicia 30,000 kg/cm ² . "The authors thank Academicia Vereshchagin for making possible this invest: Vereshchagin for his attention." Orig. art	gation and Professor N. Ye. has: 8 figures and 3 tables.
ASSOCIATION: Institut fizicheskikh problem Problems, AN SSSR); Institut fiziki vy#sokik Physics of Righ Pressures, AN SSSR)	h davleniy AN SSSR (Institute of
SUBATTTED: 05Mar63 DATE ACC	: 06sep63 ENUL: 00 OV: 012 UEUR: 013
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EWT(1)/EPR/EPF(c)/EPF(n)-2/EWP(q)/EWT(m)/EDS Ps-4/Pr-4/Fu-4 WW/JD IJP(C)/SSD 5/0120/63/000/004/0148/0151 ACCESSION NR: AP3004907 AUTHOR: Itskevich, Ye. S. TITLE: High-pressure bomb for low-temperature investigations SOURCE: Pribory*i tekhnika eksperimenta, no. 4, 1963 TOPIC TAGS: bomb, high-pressure bomb, low-temperature bomb ABSTRACT: A self-contained bomb is described which withstands up to 11,000 atm pressure and is intended for investigating electric and galvanomagnetic properties of single crystals at low temperatures. To obviate the difficulty of the lack of plasticity of the medium at low temperatures, the pressure is built up in the bomb (by means of a hydraulic press) at room temperature, then fixed mechanically, and then the bomb is transferred into a Dewar vessel. An oilkerosene mixture is used as a medium and beryllium bronze or steel, for the shell. The bomb pressure at 77K and 20K can be determined by a mangania Card 1/2

L 17324-63 ACCESSION NR: AP3004907 resistance manometer calibrated at these temperatures. Measurements of the electric resistance of gold single crystals proved that hydrostatic conditions do exist in the bomb with variations in pressure and temperature. "In conclusion, I wish to thank L. F. Vereshchagin for his constant interest in the project A. I. Likhter for his kaluable advice and kindness in lending his outfit for calibrating the manganin manometer, and also V. A. Sukhoparov and A. F. Gavrilov who played an important part in designing the bomb and in carrying out measurements." Orig. art. has: 3 figures and I table. ASSOCIATION: Institut fiziki vy*sokikh davleniy AN SSSR (Institute of High-Pressure Physics, AN SSSR) SUBMITTED: 27Aug62 DATE ACQ: 28Aug63 ENCL: 00 SUB CODE: PH NO REF SOV: 005 OTHER: 001 Card 2/2

ITSKEVICH, Ye.S.; IL'INA, M.A.; SUKHOPAROV, V.A.

Effect of pressure on the transistion temperature to the super-conductive state in Nb₂Sn and Nb - Zr alloys. Zhur. eksp. i teor. fiz. 45 no.5:1378-1379 N *63. (MIRA 17:1)

1. Institut fiziki vysokikh davleniy AN SSSR.

ITSKEVICH, Ye. S.; POPOVA, S. V.; ATABAYEVA, E. Ya.

Effect of pressure on the electric resistance of bismuth telluride. Dokl. AN SSSR 153 no. 2:306-309 N '63. (MIRA 16:12)

1. Institut fiziki vysokikh davleniy AN SSSR. Predstavleno akademikom I. V. Obreimovym.

S/0181/64/006/006/1765/1768

AUTHORS: Itskevich, Ye. S.; Atabayeva, E. Ya.; Popova, S. V.

TITIE: The effect of pressure on the electrical resistivity of bismuth selenide

SOURCE: Fizika tverdogo tela, v. 6, no. 6, 1964, 1765-1768

TOPIC TAGS: electric resistance, bismuth selenide, quasihydrostatic, silver chloride, high pressure chamber, temperature coefficient, catlinite, metallic character

ABSTRACT: The authors studied the electrical resistivity of n-Bi₂Se₃ at various pressures up to 10.4 kilobars and then between 30 and 150 kilobars. They found that at a pressure of about 100 kilobars the resistance fell abruptly, indicating a transition to the metallic state. The technique was similar to the one used for Bi₂Te₃ as given by Ye. S. Itskevich, S. V. Popova and E. Ya. Atabayeva (DAN SSSR 153, 306, 1963). The specimen was cut from bars prepared at the Institut poluprovodnikov AN SSSR (Institute of Semiconductors, AN SSSR). At room temperature it had a resistance of 5/6 10⁻⁴ohm·cm and a temperature coefficient of -70 Cord 1/4

APPROVED FOR RELEASE: 08/10/2001

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-80 microvolt/degree. Part of the specimens were prepared as mentioned above, and the others were coated with AgCl. The results of the experiments are given in Figs. 1 and 2 of the Enclosure. The authors thank L. F. Vereshchagin, corresponding member of the AN SSSR for his interest in this work, and V. A. Kuznestov and V. A. Sukhparov for taking measurements. Orig. art. has: 3 graphs.

ASSOCIATION: Institut fiziki vy*sokikh davleniy AN SSSR, Moscow (Institute of High Pressure Physics, AN SSSR)

SUBMITTED: 07Jan64

DATE ACQ: 19Jun64

ENCL: 02

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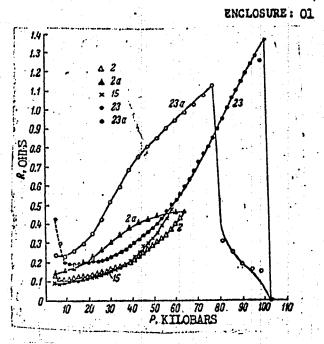
Card 2/4

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Fig. 1. Effect of quasihydrostatic pressure on the electrical conductivity of n-Bi₂Se₃ at room temper-

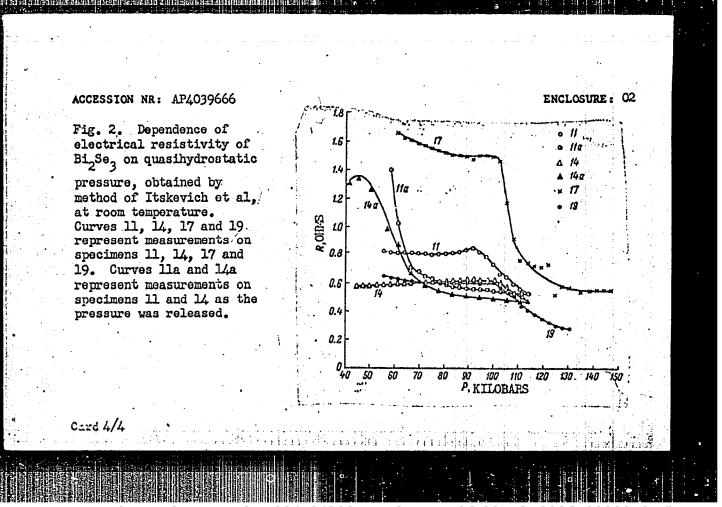
ature. (Sample coated with AgC1). Curves 2, 15, and 23 represent measurements on specimens 2, 15 and 23. Curves 2a and 23a represent measurements on specimens 2 and 23 as the pressure was released. The pressure scale is correct only for increasing pressures.



Card 3/4

APPROVED FOR RELEASE: 08/10/2001

CTA-RDP86-00513R000618920010-



\$/0181/64/006/007/2223/2225

AUTHORS: Vereshchagin, L. F.; Itskevich, Ye. S.; Atabayeva, E. Ya.; Popova, S. V.

TITLE: On a new modification of Bi₂Se₃

SOURCE: Fizika tverdogo tela, v. 6, no. 7, 1964, 2223-2225

TOPIC TAGS: bismuth inorganic compound, polymorphism, metal structure, x ray diffraction study

ABSTRACT: This is a continuation of an earlier study (FTT v. 6, 000, 1964) of the electric resistivity of Bi₂Se₃ as a function of the

pressure in the interval up to 140 kbar at room temperature. Along with the previously observed reversible transition to the metallic state observed near 100 kbar at room temperature, an irreversible polymorphic transition was observed at 800C and 120--65 kbar, to

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a new phase Bi₂Se₃ II which is metastable under normal conditions. To confirm the polymorphic nature of the transition, the sample was annealed for 2 hours in pure helium (500C), and the reverse transition Bi, Se, II - Bi, Se, I was established by x-ray diffraction. The x-ray diffraction pattern has 40 lines which could be identified in a structure of the bismuth type (Bi₂S₃), orthorhombic cell, space group Pbnm (D_{2h}^{16}) . The unit cell parameters of the new phase are $a = 11.63 \pm 0.03 \text{ Å, } b = 11.76 \pm 0.03 \text{ Å, and } c = 4.06 \pm 0.01 \text{ Å.}$ The density determined by x-ray diffraction and pycnometrically is 7.8 and 8.0 \pm 0.3 g/cm³, respectively, confirming the correctness of the proposed structure. The resistivity of the new phase is 1.2--1.5 ohm-cm, and the temperature coefficient of resistivity is negative between 0 and 100C. The data confirm the correlation between the electric properties and the crystal structure inherent in compounds A₂B₃ of elements of groups V-VI. Data on the electric properties

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s/0056/64/047/002/0455/0463

ACCESSION NR: AP4043616

AUTHORS: Brandt, N. B.; Gaydukov, Yu. P.; Itsekevich, Ye. S.; Minina, N. Ya.

TITLE: Effect of pressure on the oscillation effects in bismuth

SOURCE: Zh. eksper. i teor. fiz., v. 47, no. 2, 1964, 455-463

TOPIC TAGS: bismuth, quantum statistics, resistance, magnetic susceptibility, low temperature phenomenon, high pressure research, Eermi surface

ABSTRACT: This is a sequel of an earlier study by two of the present authors (Gaydukov and Itskevich, ZhETF, v. 45, 71, 1963) on the effects of uniform compression on the quantum oscillations of the electric resistance (Shubnikov-deHaas effect) of zinc. The present study is devoted to the effective uniform compression on the quantum oscillations of the magnetic susceptibility (pressures

Card 1/4

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1300--1600 kg/cm 2) and the electrical resistance (at 3000--7500 kg/cm²) in bismuth at liquid helium temperatures. The test procedure is described. In addition, the influence of pressure on the deHaas-van Alphen effect was investigated using a procedure described elsewhere (N. B. Brandt, Ya. G. Ponomarev, PTE, no. 6, 114, 1961). The influence of uniform compression on the quantum oscillations of the electric resistance was measured by a method of Ye. S. Itskevich (PTE, no. 4, 148, 1963). The results showed a decrease in the oscillation frequency, amounting to 37% at 7500 kg/cm². The results are interpreted on the basis of a model wherein the Fermi surface of bismuth consists of one hole and three electron ellipsoids, and the test results on the two effects in bismuth are in good mutual agreement. An analysis of the influence of uniform compression on the Fermi surface shape and on other characteristics of The possibility that bisbismuth at low temperatures is presented. muth would go over into a dielectric state at low temperatures is discussed. "We thank L. F. Vereshchagin and A. I. Shal'nikov for

Card 2/4

ACCESSION NR: AP4043616

their interest in this work and V. A. Sukharov for help with the experiments." Orig. art. has: 6 figures and 1 table.

ASSOCIATION: Moskovskiy gosudarstvenny*y universitet (Moscow State University); Institut fiziki vy*sokikh davleniy Akademii nauk SSSR (Institute of Physics of High Pressures, Academy of Sciences SSSR)

SUBMITTED: 17Mar64 ENCL: 01

SUB CODE: SS NR REF SOV: 014 OTHER: 006

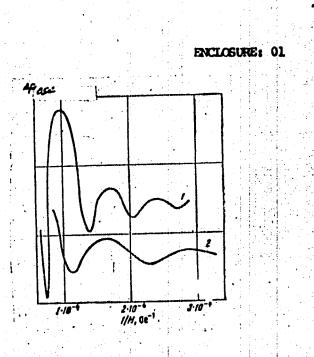
Card 3/4

Dependence of oscillating part of magnetoresistance on the reciprocal magnetic field intensity at 1.5K.

$$1 - p = 0$$

2 - p = 7500 kg/cm²

Curves shifted vertically in arbitrary fashion



APPROVED FOR RELEASE: 08/10/2001

CIA-RDP86-00513R000618920010-4"

"Change of Fermi-Surfaces of Metals Under Pressure"

Paper delivered at the High Pressure Conference, Le Creusot, France, 3-7 Aug 1965.

USSR Academy of Sciences, Moscow.

L 4083-66

ACCESSION NR: AP5021728

UR/0386/65/002/002/0067/0071

AUTHOR: Itskevich, Ye. S.; Voronovskiy, A. N.; Sukhoparov, V. A.

737 I

TITLE: Variation of low-frequency component of the electric-resistance oscillations of zinc in a magnetic field at a pressure of 16,000 kg/cm²

SOURCE: Zhurnal eksperimental'noy i teoreticheskoy fiziki. Pis'ma v redaktsiyu. Prilozheniye, v. 2, no. 2, 1965, 67-71

TOPIC TAGS: zinc, electric resistance, high pressure research, pressure effect, transverse magnetic field, magnetoresistance, quantum oscillation

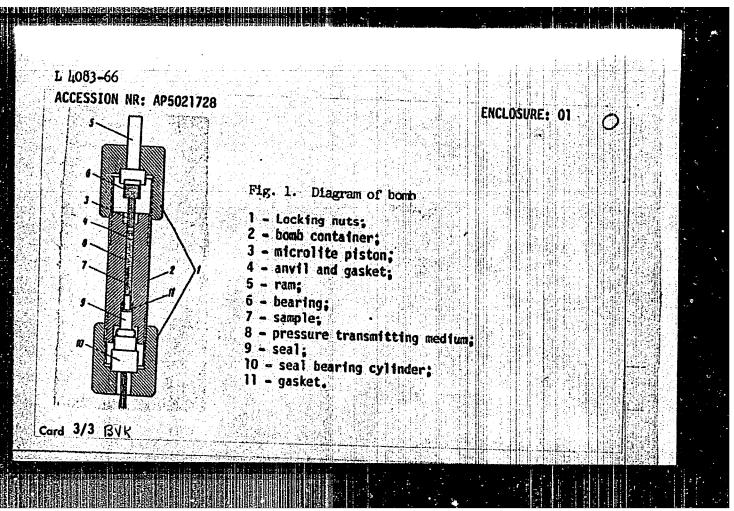
ABSTRACT: The strong influence of pressure on the frequency of the lowest-frequency quantum oscillations of the electric resistance of zinc in a transverse magnetic field, investigated earlier by one of the authors (Itskevich, with Yu P. Gaydukov, ZhETF v. 45, 71, 1963), was studied further with the aid of a new bomb capable of producing pressures up to 18,000 kg/cm² at hellium temperatures. The new bomb is illustrated in Fig. 1 of the Enclosure. Its main advantages are that its container is self-sealing and that its moving parts are made of solid non-magnetic materials. Keasurements were made without pressure and at 11,100 and 15,900 kg/cm² in fields ranging from 2000 to 11,000 be. The results show conclu-

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confirm the exi	of W. A. Harri Istence of a n	son (Phys. Rev. v eedle-like electr	. 118, 1190 1	960). The real	ons ults
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L 14962-66 EPF(n)-2/EWP(k)/EWT(1)/EWT(m)/EWP(b)/EWA(d)/WA(t) IJF(2) GG/ SOURCE CODE: UR/0386/65/002/011/0514/0519 AUTHOR: Itskevich, Ye. S.; Muzhdaba, V. H.; Sukhoparov, V. A.; Shalyt, S. S. ORG: Institute of High Pressure Physics, Academy of Sciences SSSR; Institute of Semiconductors, Academy of Sciences SSSR TITLE: Influence of hydrostatic pressure on the effective mass of electrons in InSb SOURCE: Zhurnal eksperimental'noy i teoreticheskoy fiziki. Pis'ma v redaktsiyu. Prilozheniye, v. 2, no. 11, 1965, 514-519 TOPIC TAGS: indium compound, entimonide, magnetoresistance, electron, pressure effect, magnetic field intensity 21;44,55 ABSTRACT: Data are given from an experimental study of the direct effect which hydrostatic pressure of up to 8000 kg/cm2 has on the effective mass of electrons. The experimental method was based on the new Gurevich-Firsov magnetophonon resonance phenomenon. The specimen studied was a single crystal of n-type InSb with dimensions of 2 × 2,5 × 15 mm, a concentration of 8·10¹³ cm⁻³ and a mobility of 7·10⁵ cm2/v-sec at 77°K. The relative reduction in the linear dimensions of the crystal was no greater than 0.6% at maximum pressure. Curves are given showing the trans-Card 1/2

L 14962-66 ACC NR: AP6002467 verse magnetoresistance as a function of magnetic field strength at various pressures. Formulas are given for determining the effective mass of electrons from the period of the oscillations and from the position of the individual maxima on these curves. Calculations show a change in effective mass from 0.016 to 0.025 when the pressure is changed from 1 kg/cm² to 8000 kg/cm². Since the width of the forbidden zone in this pressure interval increases by a factor of 1.5, the experimental data confirms the theoretical conclusion of direct proportionality between the effective mass of electrons and the width of the forbidden zone for an InSh crystal in this pressure interval. Orig. art. has: 3 figures, 3 tables. SUB CODE: 20/ SUBM DATE: 200ct65/ ORIG REF: 002/ OTH REF: 004

L 44810-66 EWT(1)/EWT(m)/EWP(t)/ETI IJP(c) JD/WW

ACC NR: AP6032023

SOURCE CODE: UR/0386/66/004/006/0226/0230

AUTHOR: Itskevich, Ye. S.; Vornovskiy, A. N.

ORG: Institute of High Pressure Physics, Academy of Sciences, SSSR (institut fiziki vysokikh davleniy Akademii nauk SSSR)

TITLE: Change of topology of the Fermi surface of cadmium under pressure

SOURCE: Zhurnal eksperimental'noy i teoreticheskoy fiziki. Pis'ma v redaktsiyu. Prilozheniye, v. 4, no. 6, 1966, 226-230

TOPIC TAGS: cadmium, Fermi surface, pressure effect, high pressure research, resistivity, galvanomagnetic effect

ABSTRACT: This is a continuation of earlier work (ZhETF v. 45, 71, 1963) on the angular dependence $\rho(\theta)$ of the resistivity of cadmium in strong magnetic fields. The measurements were made on four samples of pure cadmium ($\alpha = \rho_{XOOK}/\rho_{\parallel}.2K \approx (12-14)$ x 10^{3}) in a high-pressure chamber described elsewhere (PTE, 1967, in press). The sample axes were parallel to the [1120] direction. The measurements have shown that at pressures above 8 kbar and H || [0001], an additional third maximum appears on the $\rho(\theta)$ curves, as against only two at lower pressures. The relative magnitude of this maximum is practically independent of the field intensity, but does depend on the temperature. The form of the maximum does not change when the temperature is lowered. When the pressure rose above 15 kbar, splitting of the new maximum was observed. This splitting apparently does not take place below 14 kbar, since the authors were unable

Card 1/2

Card 2/2

ACC NR: AP7001955 (A)SOURCE CODE: UR/0120/66/000/006/0161/0164 AUTHOR: Itskevich, Ye. S.; Voronovskiy, A. N.; Gavrilov, A. F.; Sukhoparov, V. A. ORG: Institute of Physics of High Pressures AN SSSR, Moscow (Institut fiziki vysokikh davleniy AN SSSR) TITLE: High pressure (up to 18 Kbar) chamber for operation at liquid helium tempera-SOURCE: Pribory 1 tekhnika eksperimenta, no. 6, 1966, 161-164 TOPIC TAGS: high pressure chamber, metal, single crystal, liquid helium, temperature, beryllium bronze, corundum microlite ABSTRACT: Two models of a high-pressure (up to 18 kbar) chamber used for studying single crystals of metals and semiconductors in a magnetic field at liquid helium temperatures are described. The chambers (6.5 mm inside diameter) are made of heat-treated beryllium-bronze and the pistons are made of TSM-322 | corundum-microlite heat treated to a hardness of 75-78Rc. required pressure is created in the chamber at room temperature by a hydraulic press. The chamber is then sealed mechanically and placed in a Dewar vessel containing liquid helium. Pressure is measured by means of manganin and superconducting pressure gages. The magnitudes of anisotropy **Card** 1/2 UDC: 539.89

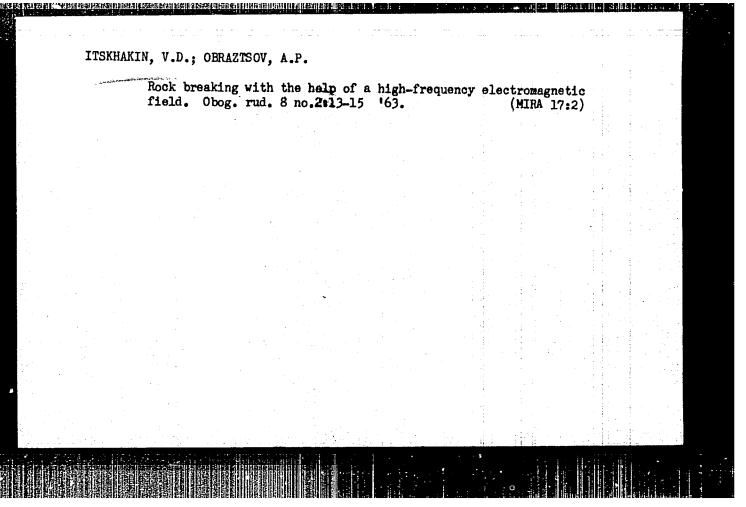
ACC NR. AP7001955,

of magnetic resistance and of quantum oscillations of electric resistance of zinc, measured in the chamber, showed that the compression was close to hydrostatic. The heat expansion of the materials used for chamber construction were tested at temperatures from 77K to 20C. It was found that the heat expansion coefficient of corundum-microlite is significantly smaller than that of beryllium-bronze. Thus, using a scoon material in the chamber should not lead to pressure losses when the temperature drops.

Orig. art. has: 4 figures and 1 table.

SUB CODE: \$\frac{\pi}{2}\$, 20/ SUBM DATE: 11Dec65/ ORIG REF: 003/ OTH REF: 003/

ATD PRESS: 5112



CIA-RDP86-00513R000618920010-4 "APPROVED FOR RELEASE: 08/10/2001

SPHALL, 6. L.

112-1-621

Translation from: Referativnyy Zhurnal, Elektrotekhnika, 1957, Nr 1,

p. 104 (USSR)

AUTHOR:

Itskhakin, V. I.

TITLE:

Tuneable Inductance Coil for the Generation of High Voltages in Testing for High-Frequency Breakdown (Nastraivayemaya katushka induktivnosti dlya polucheniya bol'shikh naprya-

zheniy pri ispytaniyakh na vysokochastotnyy proboy)

PERIODICAL: Inform.tekhn. sb. M-vo elektrotekhn. prom-sti SSSR, 1955,

Nr 83, pp. 26-28

ABSTRACT:

High-frequency high voltages are usually obtained by connecting a high-voltage lengthening coil to the high-frequency oscillator; the coil together with the capacitance of the tested object creates an auxiliary circuit tuned into resonance with the oscillator frequency. The amplitude of the output voltage is controlled by changing the mutual disposition of the coil of the output circuit of the highfrequency oscillator and of the special coupling coil. The highest attainable testing voltage is determined according

Card 1/2

√ PQXc, where U is the effective voltage to the formula U =

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CIA-RDP86-00513R000618920010-4"

112-1-621

Tuneable Inductance Coil for the Generation of High Voltages in Testing for High-Frequency Breakdown (Cont.)

in volts; Q, the quality factor of the load circuit; P, the power in watts transmitted from the oscillator into the load circuit; Xc, the capacitive reactance of the load in ohm. Since the Q factor of the load circuit is determined on the whole by the Q factor of the lengthening coil, to their preparation high-priced coil-forms with terminal blocks made of radio porcelain are usually used. A simple and inexpensive lengthening coil with a coil-form made from ordinary 10 mm plywood was successfully developed. The coil has a Q factor of about 550, is mechanically resistant, and has an electric strength between the turns of about 8 kv with a frequency of 2000 kc. A table is given permitting a simple selection of structural parameters of the lengthening coils depending on the oscillator frequency and on the capacitance of the tested object. Inductance coils with a plywood coil-form are recommended for obtaining voltages up to 50 to 70 kv from the highfrequency oscillators operating in a range of intermediate and medium-length waves. For shorter waves the use of spoolless: coils is recommended.

Card 2/2

CIA-RDP86-00513R000618920010-4 "APPROVED FOR RELEASE: 08/10/2001

AUTHOR:

Gorenshteyn, I.B., Candidate of Technical Sciences, 386

Itskhakin, V.I., Engineer and Merzheyevskiy, A.I., Candidate of Technical Sciences.

TITIE:

Delay cables. (Kabeli zaderzhki.)

are participated results that is the Hereauth that the class of the

PERIODICAL: "Vestnik Elektropromyshlennosti" (Journal of the Electrical Industry) 1957, Vol. 28, No. 4, pp. 21 - 24 (U.S.S.R.)

ABSTRACT:

In pulse radio technique artificial lines are being replaced by delay cables. These are uniform co-axial cables with a spiral internal conductor. They have a high inductance and a somewhat higher capacitance than normal cables.

The construction of delay cables is described. The inner wire is wound on an insulating core usually of polyethylene. When large delays are required a magnetic-dielectric core may be used. There are two main types of delay cable, those with thin layer insulation and an external wire which does not form a closed circuit for annular currents and those with thick layer insulation and closed circuit external wire. The thin layer insulation is usually wound from one or two tapes of polyethylene, fluoro plastic or styroflex some hundredths or tenths of a millimetre thick. Thick layer insulation usually consists of a solid polyethylene applied by extrusion. The principal data on two types of cable manufactured in the U.S.S.R. are tabulated The influence of cable design on the electrical characteristics is examined. Magnetic dielectric cores are mainly used in connection with colour television at

APPROVED FOR RELEASE: 08/10/2001

CIA-RDP86-00513R000618920010-4"

Itskhoki, Ya. S. "A new method of calculating thevolt-second characteristics of insulation," Trudy Leningr. politekhn. in-ta im. Kalinina, 1948, No.3, p. 105-14.

SO: U-3736, 21 May 53, (Letopis 'Zhurnal 'nykh Statey, no. 16, 1949).

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ITSKHOKI, A. S.

Impul'snaia tekhnika. Moskva, Sovetskoe radio, 1949, 295 p., illus.

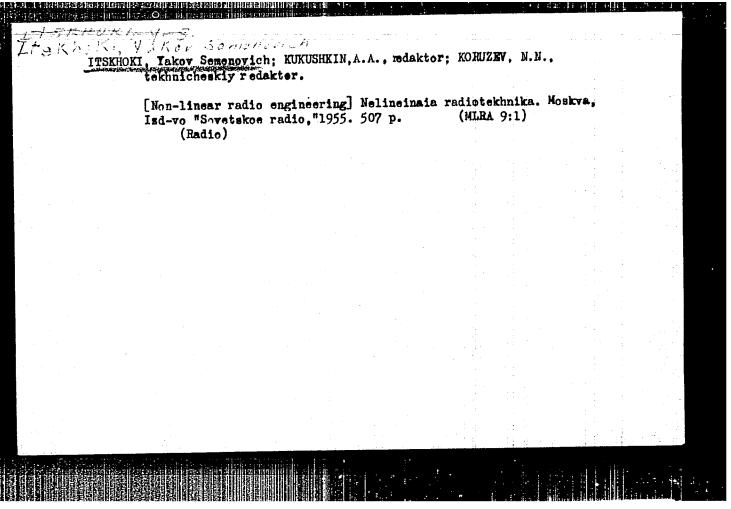
Bibliography: p. 292_293.

Title tr.: Pulse engineering.

Langla disagna ang Arcestarus, Independent mangunum industria.

TK7835.I 85

SO: Aeronautical Sciences and Aviation in the Soviet Union, Library of Congress, 1955.



AUTHOR: Itskhoki, Ya.S.

A-U Sci Conf dedicated to "Radio Day," Moscow, 20-25 May 1957. "Minimum Volume of a Pulse Transformer," TITLE :

PERIODICAL: Radiotekhnika i Elektronika, Vol. 2, No. 9, pp. 1221-1224,

(USSR). 1957,

For abstract see L.G. Stolyarov.

TSKHOKI

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108-10-8/11

AUTHOR:

Itskhoki, Ya.S., Ordinary Member of the Society

TITLE:

Smallest Measurements of Impulse-Transformers (Minimal'nyy ob"-

yem impul'snogo transformatora)

PERIODICAL:

Radiotekhnika, 1957, Vol. 12, Nr 10, pp. 66 - 84 (USSR)

ABSTRACT:

A new method for technical calculation of heavy-type impulse transformers with a minimum of their metal (iron and copper)volume is given. The author shows that constructions with 0,5 g per Watt of mean transformer power are possible. In order to realize this the usual method of calculation for impulse-transformers must be changed in such a way that the demands for the tolerable distortion of the impulse optimum must be replaced by that for reaching the minimum transformer weight. The method given here meets this demand. There are 4 tables, 12 figures

and 5 Slavic references.

SUBMITTED:

June 27, 1957

ASSOCIATION =

Nauchno-tekhnicheskoye obshchestvo radiotekhniki i elektrosvyazi

im. A.S. Popova

AVAILABLE: Card 1/1

Library of Congress

9(3)

PHASE I BOOK EXPLOITATION

SOV/2745

Itskhoki, Yakov Semenovích

Impul'snyye ustroystva (Pulse Devices) Moscow, Izd-vo "Sovetskoye radio," 1959. 727 p. Errata slip inserted. No. of copies printed not given.

Ed.: N.G. Zabolotskiy; Tech. Ed.: N.N. Koruzev.

PURPOSE: This is a textbook for the course on "Pulse Devices" ("Pulse Technique") in radio engineering vuzes.

coverage: The contents of this textbook correspond to the accepted program of the above course in several schools. The basic chapters of the book are devoted to a presentation of the methods of pulse shaping, amplifying and converting and to an analysis of corresponding pulse devices employing both vacuum tubes and semiconductor devices. Chapter 1 is devoted to investigating the basic methods of analysis of pulse processes; Chapter 2, to studying the transmission of pulses through linear systems. The book outlines the principles of operation of pulse devices and analyzes the processes occurring in them. Basic relationships are established with particular attention on the conditions for stability and reliability of operation of such devices as

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Pulse Devices

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SOV/2745

well as on the selection of proper operating conditions considering the influence of unstabilizing factors. The method of presentation of the material, instead of an encyclopedia approach with an analysis of numerous circuit variants, consists in a thorough investigation of the most important components and systems of the pulse technique, emphasizing methods of independent selection and analysis of possible alternatives. The following persons participated in writing the book: chapter 3 of the book was written by S.Ya. Shats; chapter 10, paragraphs 2, 3, 5, 6, and 7 by V.V. Grigorin-Ryabov and paragraph 8 by S.I. Viglin; chapter 11 was written by N.I. Ovchinnikov and I.A. Boloshin. The author thanks the following persons for reviewing the manuscript: L.D. Gol'dshteyn, A.A. Kharkevich, A.A. Kulikovskiy, V.N. Yakovlev, B.Kh. Krivitskiy, N.I. Ovchinnikov, S.M. Nikulin and K.A. Smogilev. There are 285 references, 230 of which are Soviet, the remaining mostly English.

TABLE OF CONTENTS:

Introd	rction		5
1.	Pulse operating conditions and their basic features	4	5
2.	Characteristic of the pulse shape		14
	Some historical data on the development of pulse technique		29
-		:	

Card 2/8.

on se	Devices SOV/2745	
h. I.	Basic Methods of Analysis of Pulse Processes	*
	denotal considerations	3 3 4 6
2.		P
3.	prietion marrior	7
	Operational method	- 2
5.	Spectral method	
6.	Relation of various methods of analysis to the corresponding circuit characteristics	8
7•	Methods of analysis of transients in radio networks	13 13
. II.	Pulse Transmission Through a Linear System	_
-1.0	Condition for an undistorted transmission of the miles	15
2.	Influence of the imperfection of the system frequency-response characteristics on the distortion of the system frequency-response charac-	15
3•	Condition for an undistorted transmission of the shape of radio-pulse envelope	150
4.	Influence of the imperfection of framework recommends	18
	the radio system on the distortion of the radio-pulse shape	188
. III	• Pulse Amplifiers	•
		192

Pulse Devices	1	SOV/2	2745		9
1. Basic parameters of pulse amplifiers				192	
				195	
	n the mulse to	canamission		204	
	n H one beene en			208	
4. Simple diagram of parallel correction	••			212	
5. Diagram of series correction6. Basic ideas on composite correction	di agrama	* .		218	
7. Use of feedback for front correction	CT CORT CONTO			221	•
	rection :			221 229	
8. Use of cathode circuit for front cor			걱	233	
9. Correction of pulse top	•			237	
10. Use of feedback for top correction				242	
11. Multistage amplifiers		4.00		248	
12. Output stage		100		250	
13. Cathode follower					
Ch. IV. Linear Methods of Conversion of Pu	lse Shape and	Parameters		262	
Ch. IV. Linear Nethous of Conversion of the	200 2-2-2			262	
1. Types of converters				263	
2. Delay lines				262	
3. Pulse transformer				305	
4. Differentiating circuits					4
1/0		4			
Card 4/8					
•					
		1 4 1	4. 1 - 1 - 1	<u> </u>	

		sov/2745		
Pulse De	vices	#=-,,,,,,,,,,		
			310	
. 5. S	hortening circuits	:	330	-
6. I	ntegrating circuits			÷ 1
			338	
Ch. V.	Linear Shaping Circuits		338	- 1
1. 1	ntroduction	d narameters	341	
2. 5	introduction that is a system of systems with distribute that in the system of companies of comp	Hatributed parameter	rs 355	
			363	
		upononuo	381	
5.	Glea of a synthesis of shaping circuits			÷ .
-			3 85	
Ch. VI.	Relaxation Oscillators		385	
	- 1 - 3 al-1 an		387	•
			394)
	- A		403	;
7	no annexator with switching inductance		409	
_			426	ś
6	Multivibrator with a cathode coupling		439)
			474	
8.	Oscillator with a secondary emission tube		1	
•				
Card 5	⁷ 8			<i>*</i>
,				44.4
•			A. A. A. A. A. A.	

Pulse I	evices	sov/2745 :		
	<i>*</i>		482	
Ch. VII	Pulse Frequency Dividers		482	
1.	Basic definitions and principle of operation	ng conditions	487	
		divider	491	
7	Colocting the Operating Conditions for the		495	
4.	Step-by-step frequency divider		· ·	
		·	500	
Ch. VI	II. Triggers		500	
	- 1 3-51-111 VAN GAN DALLIGITIES OF ATTOCAL		506	
	Symmetrical trigger with place-grid couplings		532	1
3 .	Variations in trigger circuits		537	
4,	Some trigger applications			
	and Congretors		542	
Ch. IX	. Sem -toothed Voltage and Current Generators		542	
ħ.	Introduction Saw-toothed voltage generator with a timing section of	omposed of		
/2.	Saw-toothed voltage generator with a charles	•	545	
a property	linear components Saw-toothed voltage generator with a current-stabilize	ing nonlinear		
(3.	Saw-toothed voltage generator with	•	547	
- S	component		552	4.3
- 44 کر	Compensating emf method			14.
/	•1-			
Card 6	9/8			1
				: 1
		•		
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	Devices SOV/2745
	Method of capacitive ("wattless") feedback between the tube plate and
5•	
	grid.
6.	Phantastron circuit Phantastron with a cathode follower
7.	Basic calculation relationships in the phantastron
8.	"Sanatron" (a two-tube phantastron circuit)
9.	Generation of linearly-changing current
10.	
	Nonlinear Methods of Changing Voltage Shape and Pulse Parameters
Ch. X	NONLINEAR Methods of charleting version was
_	Introduction
2.	Limiters Shaping pulse by limiting and differentiating sinusoidal voltage
₹•	m 1 4
4.	Peak-transformers Calibration pulse-shaping by the method of impact excitation of the
_	Calibration burse-suching of the mountains
5.	andlineous ofrmit
_	oscillatory circuit
6.	Electron methods of pulse delay
6. 7.	Electron methods of pulse delay Level fixators
6.	Electron methods of pulse delay Level fixators
6. 7. 8.	Electron methods of pulse delay Level fixators

Pulse Devices 1. Introduction 2. Voltampere characteristics of emitter circ sistor 3. Possible balanced states of a circuit with Pulse systems with point-contact transistor		660 662
2. Voltampere characteristics of emitter circ sistor 3. Possible balanced states of a circuit with		662
3. Possible balanced states of a circuit with	noint-contact transistor	
not an arreture with noint-contact translate	pormo cambado or anti-	668 671
We Edited placement and the same	rs :	686
5. Special features of pulse systems with jun 6. Multivibrator with junction transistors	GCIOU CLUMBIB COLO	686 688
7. Miltivibrator with emitter coupling		698
8. Trigger with collector-base coupling		703 707
9. Blocking-oscillator		
Appendices		
Appendix 1		711
		713
Appendix 2		714
Appendix 3		(ite
AVAILABLE: Library of Congress		JP/Jb
		1-8-60
Card 8/8		
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MORUGIN, L.A. Prinimal uchastiye LEZIN, Yu.S.; ITSKHOKI, Ya.S., prof., doktor tekhn. nauk, retsenzent; KRIZE, S.N., prof., doktor tekhn. nauk, retsenzent; SUKHANOV, Yu.I., red.; SAUROV, B.V., tekhn. red.

[Pulse systems with delayed feedback] Impul'snye ustroistva s zapazdyvaiushchei obratnoi sviaz'iu. Moskva, Izd-vo "Sovetskoe radio,"

(MIRA 14:12)

(Pulse techniques (Electronics)) (Delay lines)

B34005/62/007/001/002/027 D246/D301

6.9200

AUTHOR:

Itskhoki, Ya.S.

TITLE:

Probability of n-overlapping of chaotic pulses of random duration and the distribution of their over-

lapping length

PERIODICAL:

Radiotekhnika, i elektronika, v. 7, no. 1, 1962,

16 - 24

TEXT: The present work gives a general distribution law and the problem is worked out for pulses of random duration. The author first finds the distribution law for two channels, assuming that the length distributions are independent and the distribution of the starting time is Poissonian. The expression is:

$$\Psi(z) = \frac{1}{\overline{X}_{1} + \overline{X}_{2}} \left[2\Psi_{1}(z) \Psi_{2}(z) + f_{1}(z) \int_{z}^{x_{2m}} \Psi_{2}(x) dx + f_{2}(z) \int_{z}^{x_{1m}} \Psi_{1}(x) dx \right]. \tag{11}$$

where \overline{X}_1 and \overline{X}_2 : mathematical expectation for X and Y, which take Card 1/3

34025 S/109/62/007/001/002/027 D246/D301

Probability of n-overlapping of ..

values x and y and $Y_i(z) = 1 - \frac{z}{0}$ $f_i(y)$ dy where $f_i(x_i)$: distribution law for the duration (x_i) of pulses in a particular channel. Using (11) and knowing $W_{n-1}(z)$ (for n-1 channels) one can obtain $W_n(z)$. It essentially depends on $f_i(x_i)$. Then the author finds the probability p_2 of overlapping pulses in two channels, when the duration is regulated by the laws $f_i(x_i)$ (i = 1,2). The probability for pulses of random duration in n channels can be found by averaging p_n for duration x_i in all channels. This probability is determined solely by the average value of pulse duration and their average repetition frequency:

 $p_{\mathbf{n}} = \lambda^{\mathbf{n}-1} \sum_{i=1}^{\mathbf{n}} \frac{1}{\overline{X}_{i}} \prod_{i=1}^{\mathbf{n}} \overline{X}_{i}. \tag{17}$

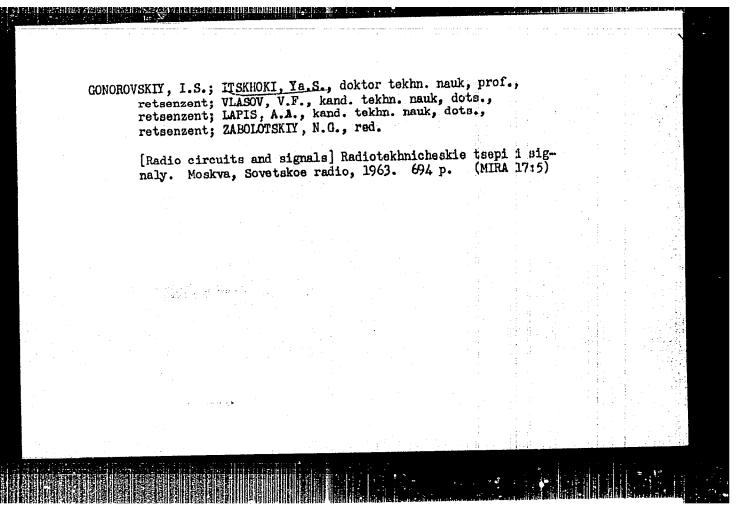
Card 2/3

VLASOV, Viktor Fedorovich; Prinimal uchastiye OVCHINNIKOV, N.I.,
dots.; IZYIMOV, N.M., prof., retsenzent; ITSKHKKI, Ya.S.,
prof., nauchny red.; LARIONOV, G.Ye., tekhn. red.

[Course in radio engineering] Kurs radiotekhniki. Moskva, Gos.
energ. izd-vo, 1962. 927 p. (MIRA 15:3)

(Radio)

IA-RDP86-00513R000618920010-4"



ITSKHOKI, Ya.S.

Choice of the duration of pulse normalisation in the initial treatment of radar pulse packs. Radiotekhnika 18 no.12:57-65 D '63. (MIRA 17:1)

1. Deystvitel'ny, chlen Nauchno-tekhnicheskogo obshchestva radiotekhniki i elektrosvyazi imeni Popova.

CONCROVSKIY, I.S.; ITSKHOKI, Ya.S., doktor tekhn. nauk, prof.,
retsenzent; VLASOV, V.F., kand. tekhn. nauk, doto.,
retsenzent; LAPIS, A.A., kand. tekhn. nauk, dots.,
retsenzent; ZABOLOTSKIY, N.G., red.

[Radio circuits and signals] Radiotekhnicheskie tsepi i
signaly. 1zd.2., ispr. Moskva, Sovetskoe radio, 1964.
694 p. (MIRA 17:11)

[1]

ACCESSION NR: AP4040455

5/0108/64/019/006/0003/0010

AUTHOR: Itskhoki, Ya. S. (Active member)

TITLE: Frequency of false signal appearance at the output of the initial processing device of radar pulse packets

SOURCE: Radiotekhnika, v. 19, no. 6, 1964, 3-10

TOPIC TAGS: radar, radar pulse packet, radar signal, false signal, false signal frequency, pulse coincidence probability, probability theory, logical circuit, noise packet

ABSTRACT: On the basis of the pulse-coincidence probability theory, an all-purpose formula has been developed for calculating the average frequency of false signals at the cutput of the selecting device of the type k-out-of-m:

$$F_{fg} = C_{m-1}^{k-1} \frac{k}{T_m} \rho_m^k v^{k-1} \left(1 - \frac{k+3}{k} \rho_m v \right)^{m-k} \left(1 - \frac{k}{k-1} \rho_m v \right)_0$$

Card 1/4

ACCESSION NR: AP4040455

The formula is compared with known approximate semiempirical formulas of the type

[2]

where Δf is the energy landwidth of the receiver's IF amplifier and P_{fg} is the probability of detecting the false signal (the noise pulse packet), the beginning of which is fixed at a given azimuth position. Formula [2] contains only the two magnitudes Δf and P_{fg} , both of which are relatively easy to determine. However, formula 2 is based on assumptions which are difficult to analyze and whose reliability is questionable. V. N. Dymchishin [Radiotekhnika i Elektronika, v. 4, no. 6, 1959] developed an analytical method of determining the average frequency of tripping (P_{gg}) of a logical circuit of the k/m type, but its usefulness is subject to objections because Dymchishin's formula expresses the average rate of triggering the logical circuit and not the rate of false signals. It is, therefore, necessary to obtain a more accurate formula for determining the average frequency of false signals. The author based his formula [1] on a logical circuit into which a random sequence of fixed rectangular noise pulses Card 2/4

ACCESSION NR: AP4040455

enters whose duration is constant. The distribution along the time axis of the moments of pulse appearance is of the Poisson-type, and the average pulse-repetition rate is assumed to be known. It is also assumed that the fixed noise pulses are noncorrelated. The condition of triggering this logical circuit may be formulated as follows: the circuit responds when coincidence of not less than k pulses in m channels with a duration Tmin is established. In order to find the average rate of false signals, the probability of only the first noise packet, which triggers the logical circuit during every detection, need be determined. The probability of forming a false signal is

$$P_{av}$$
, 1 = $p_Aq_B^{m-k}q_C$.

from which the average frequency of false signal appearance is ex-

where v is the average frequency of appearance of fixed noise pulses

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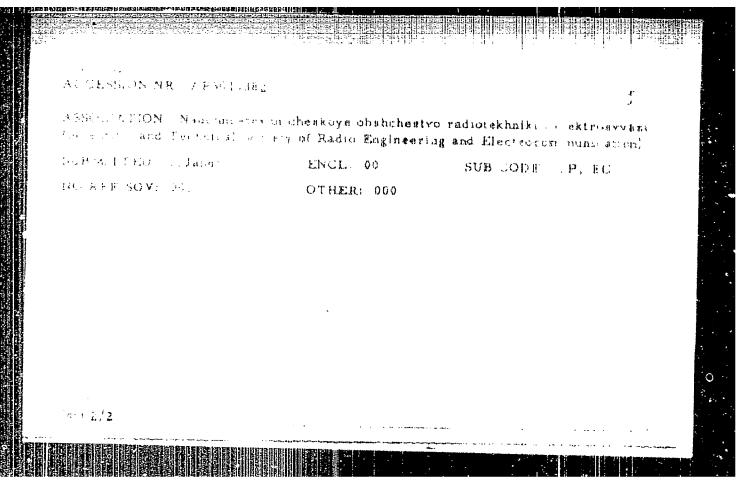
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conversion nonlinearity to a few hundreds of one per cent; however, such a result presupposes a very accurate — to a few tenths of one per cent — selection of the configuration in the configuration in the configuration of the ambient amprical formula) for the above resistor and configuration and configuration of the ambient at theoretically promise a further cutting of the configuration of the configurati

Cara 1/2



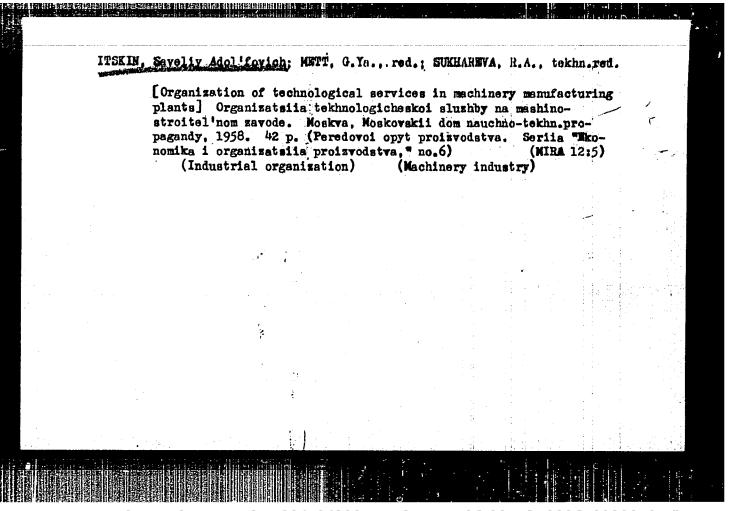
ITSKIN, S.A.

Potochnye metody raboty na mnogonomenklaturnykh uchastkakh mekhanicheskoi obrabotki. (Vestn. Mash., 1949, no. 6, p. (60-67)

Assembly-line methods in various sections of mechanical working.

DLC: TN4. V4

SO: Manufacturing and Mechanical Engineering in the Soviet Union, Library of Congress, 1953.

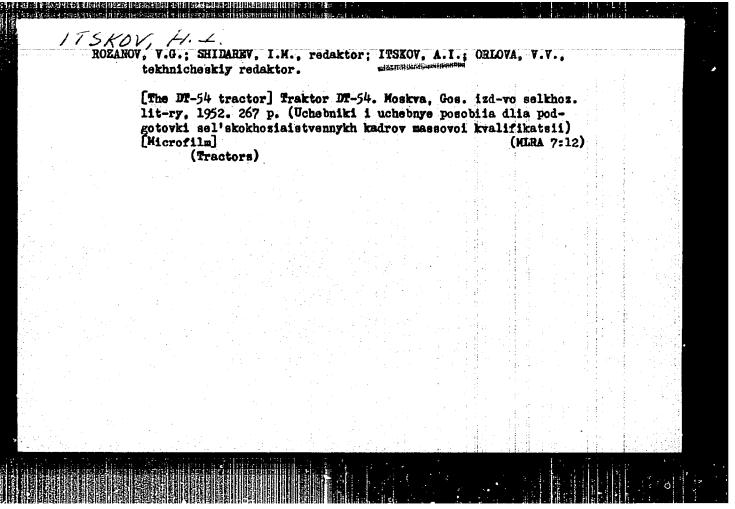


BEHKHMAN, D.L., dotsent (Leningrad); ITSKINA, R.S. (Leningrad);
KAZARNOVSKAYA, O.S. (Leningrad); PERRHUNOVA, A.I. (Leningrad);
ROTENFEL'D, M.Z. (Leningrad).

Treatment of tuberculous meningitis in adults. Klin.med. 31
no.12:31-36 D *53. (MIRA 7:1)

1. Is tuberkulesnogo otdeleniya bol'nitsy im. Kuybysheva.

(Tuberculosis) (Streptomycin) (Meningitis)



ITSKOV, L.Ya.

Vibrating bunkers with an electromagnetic drive. Standartizatsiia 27 no.9:12-13 S '63. (MIRA 16:10)

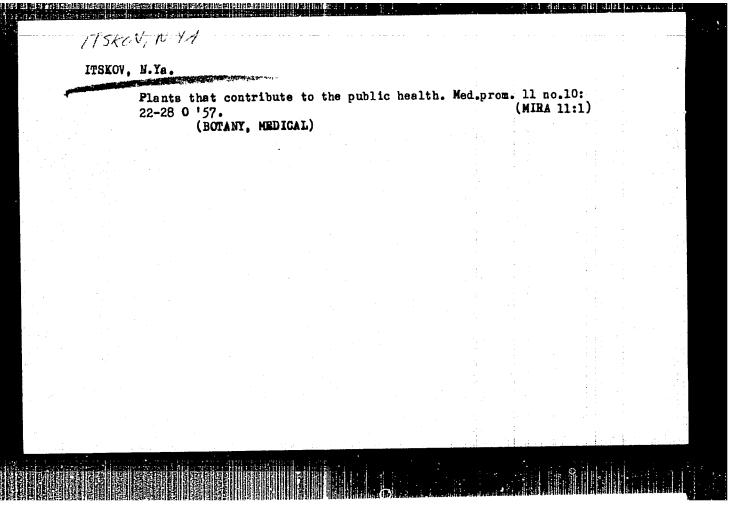
GERASIMENKO, I.I.; LIBIZOV, N.I.; NIKOL'SKAYA, B.S.; SATSYFEROV, P.A.

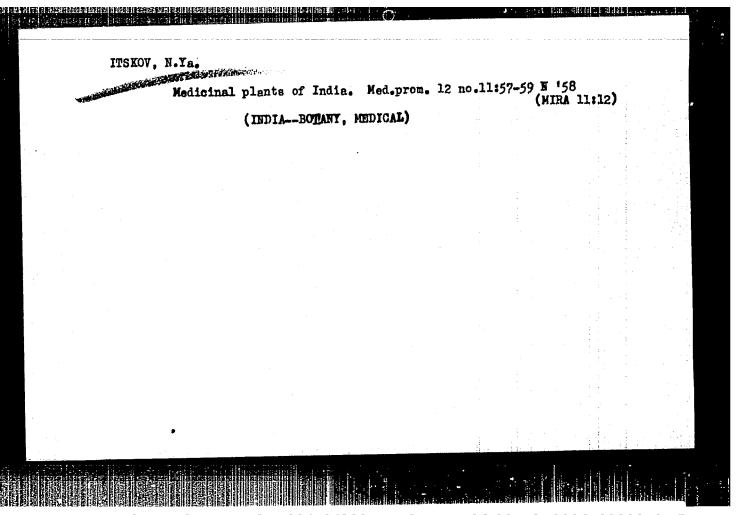
[deceased]; ITSKOV, N.Ya, kandidat sel'skokhosynystvennykh nauk, redaktor; TUROVA, T.M. dittor meditsinskiy nauk, redaktor; ZHUKOV, G.I., redaktor; EEL'CHIKOVA, Yu.S., tekhnicheskiy redaktor

[Indian datura (D. innozia Mill] Durman indelskii. Fod red. N.IA.
Itskova i A.D.Turovoi. Moskva, Gos. izd-vo med. lit-ry, 1953. 77 p.

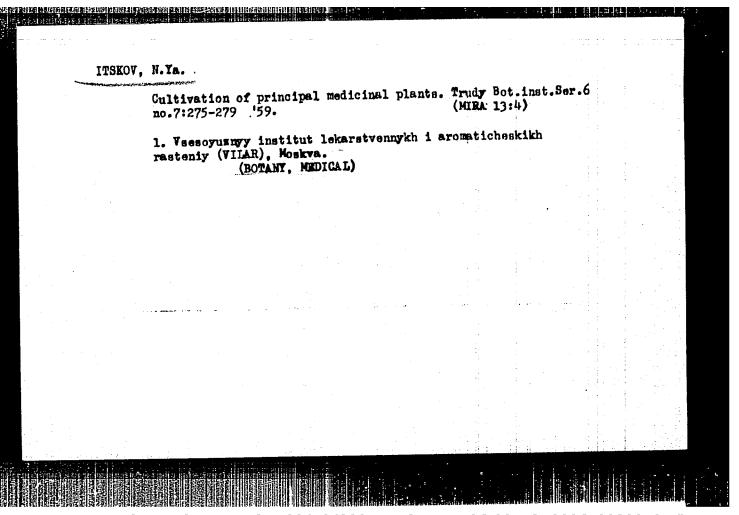
[Microfilm] (MERA 7:10)

(Datura)





APPROVED FOR RELEASE: 08/10/2001 CIA-RDP86-00513R000618920010-4"



Most important medicinal plants in the scientific and popular medicine of India. Biul.glav.bot.sada no.43:88-93 '61. (MIRA 15:2)

1. Vsesoyuznyy nauchno-issledovatel'skiy institut lekarstvennykh i aromaticheskikh rasteniy. (INDIA-BOTANY, MEDICAL)

APPROVED FOR RELEASE: 08/10/2001 CIA-RDP86-00513R000618920010-4"

Significance of the circulation factor in the genesis of some forms of subfebrile condition. Terap.arkh. 28 no.3:59-66 '56. 1. Iz kafedry propedevtiki vnutrennikh belezney (nach. chlenkorrespondent AME SSSR prof. N.M.Savitskiy) Voyenno-meditsinskoy ordena lenina akademii imeni S.M.Kārova. (FEVER subfebrile, circ. factor in genesis) (BLOOD GIRCULATION circ. factor in genesis of subfebrile fever)

ITSKOV, P.I. kand med nauk

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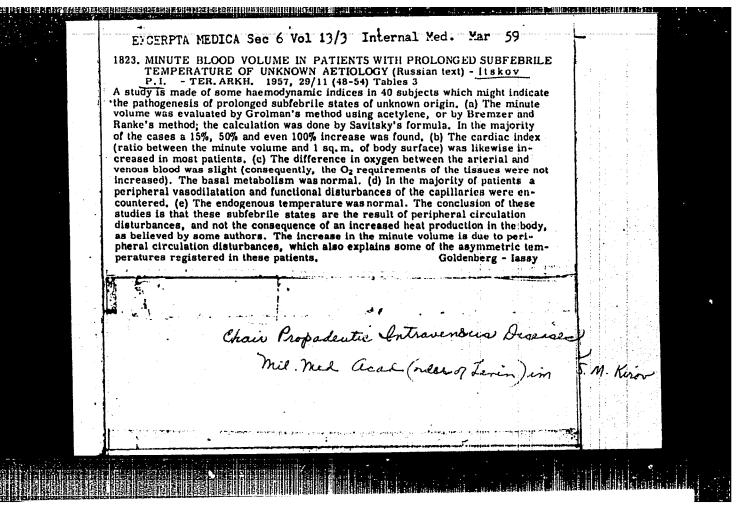
Role of the functional state of the small peripheral vessels in the development of prolonged subfebrility and methods for its determination. Terap.arkh. 29 no.2:51-56 '57. (MIRA 11:1)

1. Iz kafedry propedevtiki vnutrennikh bolezney (nach. - chlenkorrespondent AMN SSSR prof. N.N.Savitskiy) Veyenno-meditsinskoy ordena Lenina akademii imeni S.M.Kirova.

(BLOOD VESSELS, physiology, small peripheral vessels in physiol. hypothermia (Rus)) (BODY TEMPERATURE,

hypothermia, role of small peripheral blood vessels (Rus))

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CIA-RDP86-00513R000618920010-4 "APPROVED FOR RELEASE: 08/10/2001

USSR/Human and Animal Physiology. Thermoregulation

ary take take at Impressmentally (1992) 1990

T-3

Abs Jour : Ref Zhur - Diol., No 14, 1958, No 65055

: Itskov P.I. Author

Inst : A Method for Measuring Castruc Temperature Title

Orig Pub : Fiziol. zh. SSSR, 1957, 43, No 6, 586-588

Abstract : In order to measure gastric temperatures, use was made of a differential thermocouple which consists of two or several thermocouples connected in such a way that their e.n.f.'s were directed to meet each other. In order to make the entire arrangement more sensitive, six thermocouples were joined in series, with three in a group. It is more convenient to employ a galvanometer with two windings on a carriage-one of the order of 100 lhms and the other of lowolim winding (5 ohms). The compensatory e.m.f. was drawn from a potentiometer to the high-ohn winding and from the thermocouple to the low-ohm winding. Gastric temperature was

measured in the basal metabolic state; a tube of the duodenal

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Mil Med. OL Acad im 5. M. Kerow

CIA-RDP86-00513R000618920010-4"

APPROVED FOR RELEASE: 08/10/2001

USSR/Human and Animal Physiology. Thermoregulation

T-3

Abs Jour : Ref Zhur - Diol., No 14, 1958, No 65055

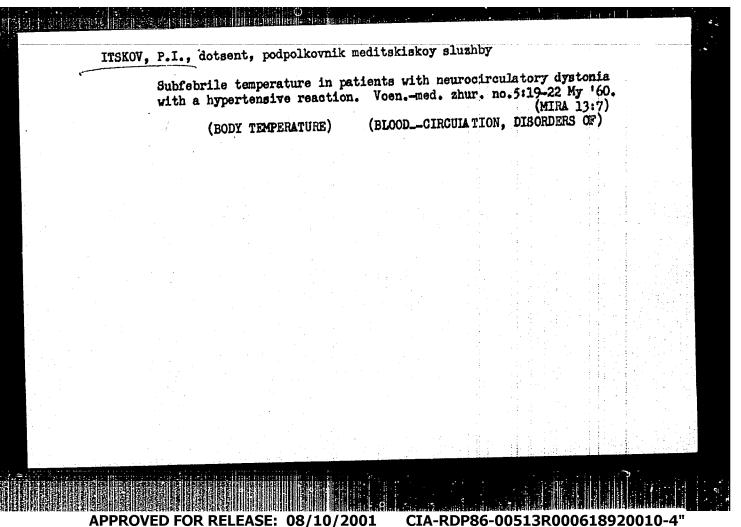
type with the differential thermocouple was introduced into a casting subject to a length of 40 to 60 cm depending upon the patient's size. It is important that the thermocouple be approximately in the region of the gastric fundus. Data obtained in examination of individuals with normal temperatures showed that the castric temperature did not exceed 37.5°, and more frequently was 37.4°. The mean value of fluctuations in auxiliary temperature was 0.5°. The gastric temperature, according to the data of measurements made over a period of 3 to 4 hours, was more stable than the auxiliary, oral and rectal temperatures. Measurement of the gastric temperature with a thermoelectric apparatus with an accuracy of 0.01° is a very convenient and precise method of investigation—F.I. Mumiadze

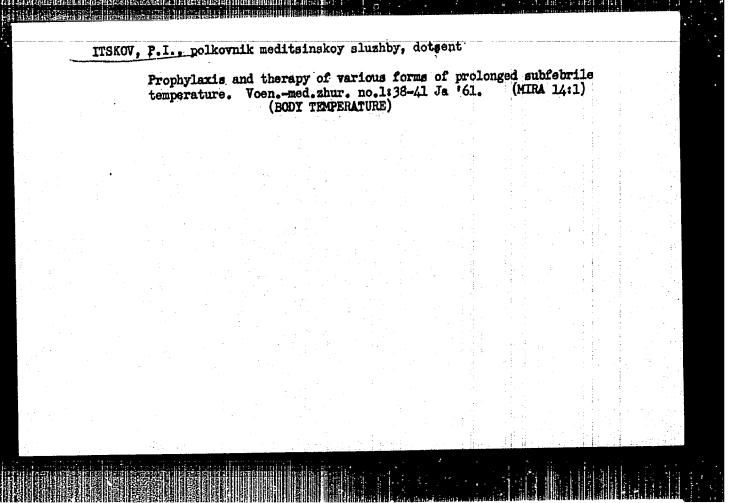
Card

: 2/2

12

APPROVED FOR RELEASE: 08/10/2001 CIA-RDP86-00513R000618920010-4"





ITSKOV, P.I., dotsent (Leningrad) Subfebrile temperature in thyrotoxicosis. Probl.endok.i gorm. (MIRA 1498)

7 no.4:73-77 161.

1. Iz kafedry popedevtiki vnutrennikh bolezney (nach. - deystvitel'nyy chlen AMN SSSR zasluzhennyy deyatel' nauki prof. N.N. Savitskiy) Voyenno-meditsinskoy ordena Lenina akademii imeni S.M. Kirova.

(BODY TEMPERATURE) (THYROID GLAND-DISEASES)

CIA-RDP86-00513R000618920010-4" APPROVED FOR RELEASE: 08/10/2001

CHUMAK, Mariya Mikhaylovna; ITSKOV, Yakov Zakharovich; FUGINA, V.V., red.

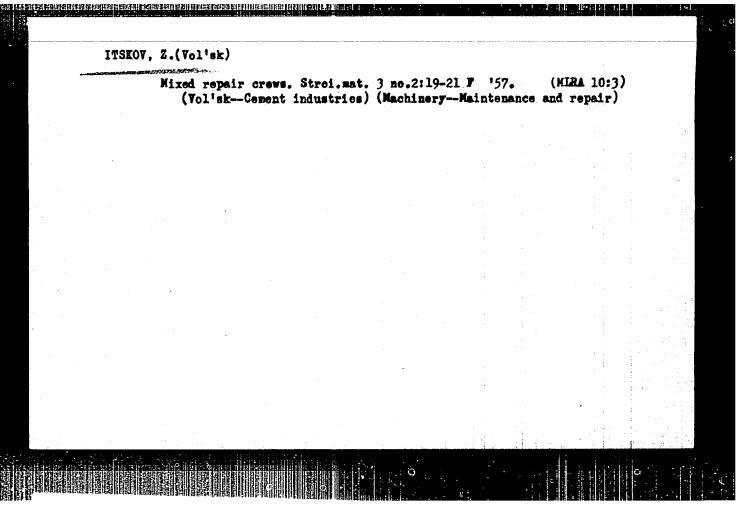
[Work organization in a Central District Hospital; experience in the work of the Vizhnitas Hospital in Chernovtsy Province] Organizatiia raboty tentral noi raiomoi bol'nitsy; opyt raboty Vizhnitskoi bol'nitsy Chernovitskoi oblasti. Moskva, 1965. 191 p.

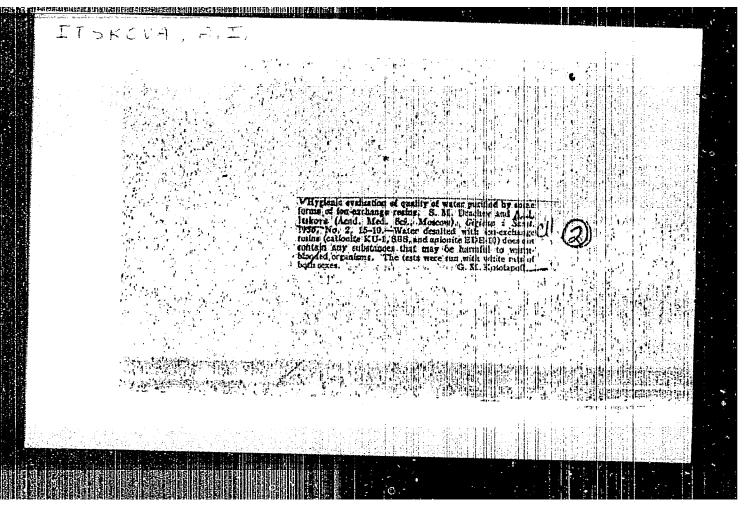
(MIRA 18:8)

ITSKOV, Ye.D., inzh.; MAKEYEV, A.V., inzh.; GUBERMAN, F.S., inzh.;
GURIN, M.A., kand. tekhn. nauk

The VP-25 vibratory-percussion machine for loosening frozen grounds. Stroi. i dor. mash. 10 no.9:5-6 S'65.

(MIRA 18:10)





ITSKOVA, A.I., kandidat meditsinskikh nauk

Manager Committee

Basis for hygienic standards for wind protection measures. Gig. i san. 21 no.9:11-18 S 156. (MIRA 9:10)

1. Is fisiologicheskoy laboratorii Institute obshchey i kommunalincy gigiyeny AME SSSR. (CLIMATE, eff.

cold wind eff., control in Russia)

Observations are reported on the effect of wind of high velocity at different atmospheric temperatures on respiration, gas exchange and heat regulation in man. An attempt is made to establish hygienic standards and certain recommendations are put forward in connection with a series of individual and collective measures for protection against wind.

ITSKOVA, A. I., RAFOPORT, K. A., SKVORTSOVA, N. N., DRACHEV, S. M., KONDROR, I. S., SOLTYSSKIY, YE. I., KOLTUNOVA, A. S.

"Hygienic Standardization of the Contnet of Mineral Salts in the Drinking Water."

report submitted at the 13th All-Union Congress of Hygienists, Epidemiologists and Infectionists, 1959.

DRACHEV, S.M., prof.; ITSKOVA, A.I., kand.med.nauk; SOLOGUB, A.M., kand.med.nauk

Some hygienic problems of water supply in contitions of the Far North. Cig.i san. 25 no.7:95-97 Jl '60.

1. Iz Instituta obshchey i kommunal'noy gigiyeny imeni A.N.

ananthing the registration of the registration

ITSKOVA, A.I.; DRACHEV, S.M.

Hygienic requirements in organizing drinking water supply in the Far North. Probl. Sev. no.6:66-70 '62. (MIRA 16:8)

1. Institut obshchey i kommunal noy gigiyeny imeni A.N. Sysina

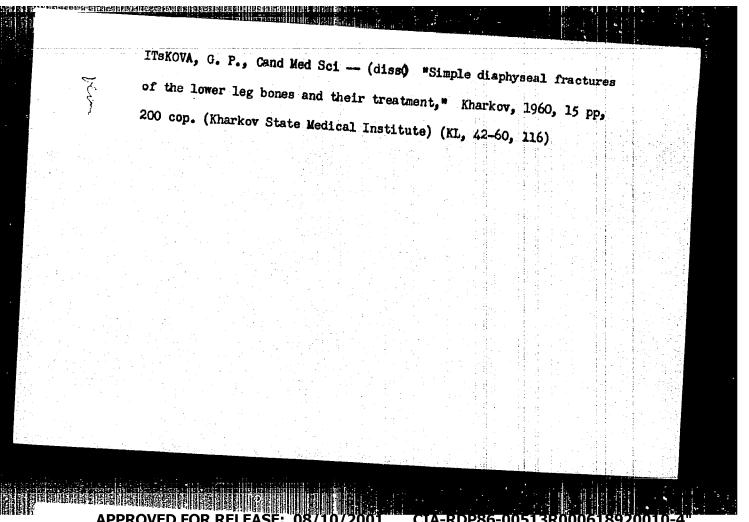
(RUSSIA, NORTHERN_WATER SUPPLY)

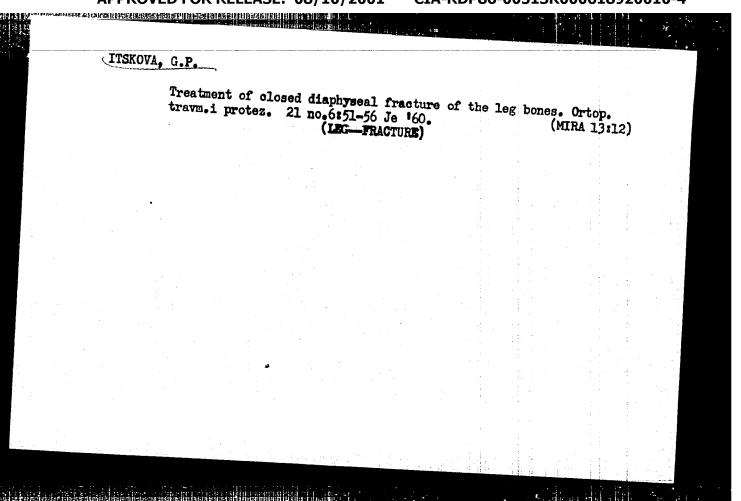
38697-66 EWT(m)/EWP(j) 2297 ACC NR: AP6021416 SOURCE CODE: UR/0413/66/000/011/0020/0020 INVENTOR: Mandel'baum, Ya. A.; Mel'nikov, N. N.; Itskova, A. L. ORG: none TITLE: Preparative method for higher dialkylphosphite. Class 12, No. 182151 SOURCE: Izobreteniya, promyshlennyye obraztsy, tovarnyye znaki, no. 11, 1966, 20 TOPIC TAGS: dialkylphosphite, methyl alcohol, higher alcohol ABSTRACT: An Author Certificate has been issued for a preparative method of higher dialkylphosphites involving the treatment of phosphorus trichloride with a mixture of 1 mol methyl alcohol and 2 mols higher alcohol. SUB CODE: 07/ SUBM DATE: 14Jun62/ 547.268'118.07 CIA-RDP86-00513R000618920010-4 MANDEL BAUM, Ya.A.; GRAPOV, A.F.; ITSKOVA, A.L.

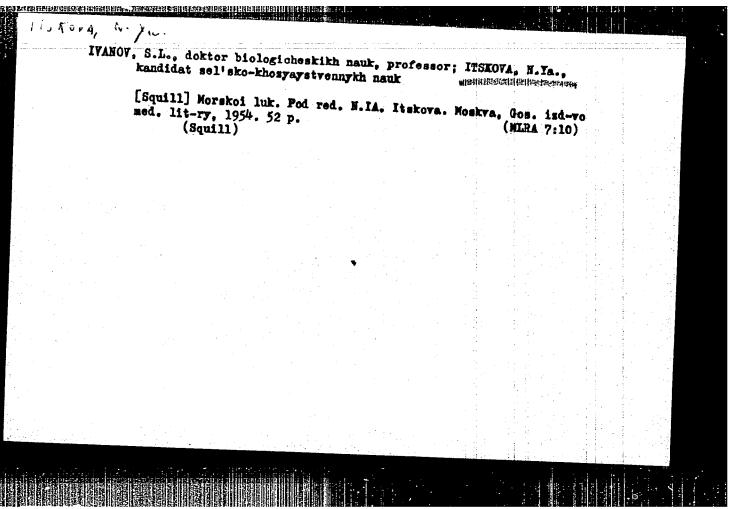
Determination of phosphorus in organic compounds by photometry. Zhur. anal. khim. 20 no.8:873-874 165. (MIRA 18:10)

1. Vsesoyuznyy nauchno-issledovatel'skiy institut khimicheskikh sredstv zashchity rasteniy, Moskva.

CIA-RDPX6-005 13R0006 189200 TO-



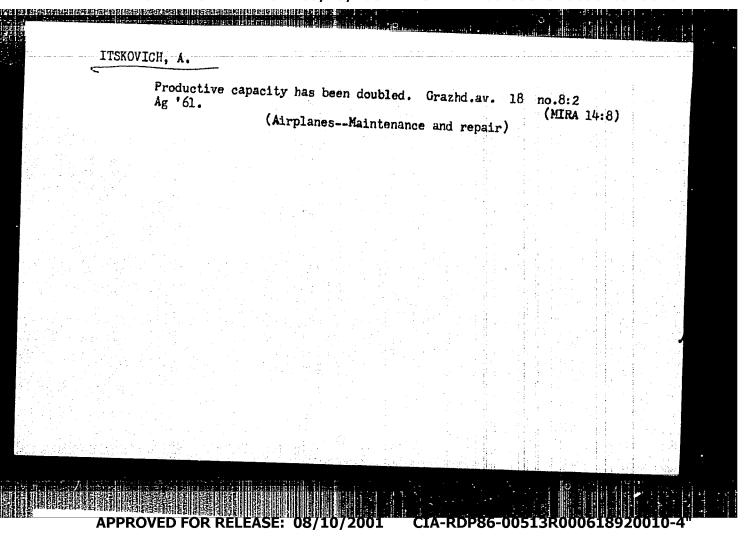




MAKAROV, V.; MANDEL', O.; ITSKOVICH, A.; PANAYOTI, Yu.

Observation of eclipsing variable stars. Astron. teir. no.187:16-17 D 157. (MIRA 11:6)

1. Kollektiv nablyudateley Otdeleniya Vsesoyusnogo astronomogeodezicheskogo obshchestva, Odessa. (Stars, Variable)



CIA-RDP86-00513R000618920010-4 "APPROVED FOR RELEASE: 08/10/2001

Subject

USSR/Medicine

AID P - 2625

Card 1/2

Pub. 37 - 2/22

Author

Itskovich, A. A., Kand. Mad. Sci., Honored Physician,

Title .

Investigation of the stimulation of the olfactory analyzer as a method for hygienic evaluation of

Periodical

: Gig. i san., 8, 9-11, Ag 1955

Abstract

Describes tests performed for determining the sense of smell of 4 groups of subjects: workers and technicians of a coke plant, neighborhood residents, neighborhood schoolchildren, and workers of the Sanitation Institute not subjected to air pollution. The tests were made by the El'sberg-Levi instrument as modified by the Institute of Industrial Hygiene and Occupational Diseases, Acad. Med. Sci., USSR. It was demonstrated that the health-protecting zone of 1,000 m. established for coke plants is insufficient. Table. 5 refs., 1933 - 1952.

APPROVED FOR RELEASE: 08/10/2001 CIA-RDP86-00513R00061892

Gig. i san., 8, 9-11, Ag 1955

AID P - 2625

Card 2/2 Pub. 37 - 2/22

Institution: Novosibirsk Sciensific Research Sanitation Institute

Submitted

: D 3, 1954

APPROVED FOR RELEASE: 08/10/2001 CIA-RDP86-00513R000618920010-4"

ITSKOVICH, A.A.; VINOGRADOVA, V.A.

Establishing permissible concentration of phenols in the atmosphere. Okhr. prir. Sib. i Dal' Vost. no.1:139-145 '62.
(MIRA 17:5)

